

2 位双向电压电平转换器

查询样品: **SN74AVC2T244**

特性

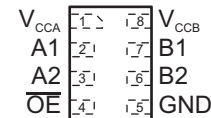
- 工作在较宽 V_{CC} 范围 **0.9 V 至 3.6 V**
- 低静态功耗, 最大 **6- μ A I_{CC}**
- 输出使能特性允许用户关闭输出以减少能耗
- **3.0 V** 电压下 **± 24 mA** 的输出驱动
- I_{off} 支持部分断电模式运行
- 输入滞后允许慢速输入转换时间和更好的输入端抗噪性
- 最大数据率
 - **380 Mbps (1.8-V 至 3.3-V 转换)**
 - **200 Mbps (<1.8-V 至 3.3-V 转换)**
 - **200 Mbps (转换至 2.5 V 或者 1.8 V)**
 - **150 Mbps (转换至 1.5 V)**
 - **100 Mbps (转换至 1.2 V)**

- 锁断性能超过 **100mA** (符合 **JESD 78 Class II** 规范的要求)
- **ESD** 保护等级超过 **JESD 22** 标准的要求
 - **5000-V** 人体模式 (**A114-A**)

应用范围

- 手持通话器, 智能手机, 平板电脑, 服务器

DQE/DQM 封装
(顶视图)



说明/订购信息

这个 2-位单项转换器使用 2 个分开的可配置电源轨。A 端口用于跟踪 V_{CCA} 。 V_{CCA} 接收从 0.9 V 至 3.6 V 间的任一电源电压。B 端口用于跟踪 V_{CCB} 。 V_{CCB} 接收从 0.9 V 至 3.6 V 间的任一电源电压。这将允许 0.9-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V 和 3.6-V 电压结点间的低压双向转换。对 SN74AVC2T244 而言, 当输出使能 (\overline{OE}) 输入为低时, 所有输出均处于高阻抗状态。SN74AVC2T244 的 \overline{OE} 输入电路参考 V_{CCA} 而设计。该器件的技术规格针对采用 I_{off} 的部分断电应用而全面拟订。 I_{off} 电路负责停用输出, 从而可防止破坏性的电流在其断电时通过器件回流。

订购信息⁽¹⁾

T_A	封装 ⁽²⁾	可订购部件号	正面标记
-40°C 至 85°C	DQE – MicroQFN	SN74AVC2T244DQER	VA
	DQM – MicroQFN	SN74AVC2T244DQMR	VAH

(1) 有关最新的封装和订购信息, 请参阅本文档结尾的“封装选项附录”, 或访问 TI 网站: www.ti.com。

(2) 封装图样、热数据和符号可登录 www.ti.com/packaging 获取。



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DEVICE INFORMATION

PIN DESCRIPTION

PIN	FUNCTION
VCCA	Input Port DC Power Supply
VCCB	Output Port DC Power Supply
GND	Ground
An	Input Port
Bn	Output Port
OE	Output Enable

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
Voltage	DC Supply voltage, V_{CCA} , V_{CCB}		–0.5	4.6	V
	DC Input voltage, V_I	A_n	–0.5	4.6	V
	Control Input, V_C	\overline{OE}	–0.5	4.6	V
	DC Output voltage, V_O , $V_{CCA} = V_{CCB} = 0$	(Power Down) B_n	–0.5	4.6	V
		(Active Mode) B_n	–0.5	4.6	
		3-State Mode B_n	–0.5	4.6	
	DC Input Diode current, I_{IK}	$V_I < GND$		–20	mA
	DC Output Diode current, I_{OK}	$V_O < GND$		–50	mA
	DC Output Source/Sink current, I_O			±50	mA
	DC Supply current per supply pin, I_{CCA} , I_{CCB}			±100	mA
I_{GND}	DC Ground current per ground pin			±100	mA
T_{stg}	Storage temperature range		–65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V_{CCA} , V_{CCB}	Positive DC Supply voltage		0.9	3.6	V
V_I	Bus input voltage		GND	3.6	V
V_I	Input voltage		GND	3.6	V
V_C	Control input	\overline{OE}	GND	3.6	V
V_O	Bus output voltage	(Power Down Mode) B_n	GND	3.6	V
		(Active Mode) B_n	GND	V_{CCB}	V
		3-State Mode B_n	GND	3.6	V
T_A	Operating free-air temperature		–40	85	°C
$\Delta t/\Delta v$	Input transition rise or fall rate V_I from 30% to 70% of V_{CC} ; $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		0	10	nS

ELECTRICAL CHARACTERISTICS^{(1) (2)}

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA} (V)	V _{CCB} (V)	–40°C to 85°C		UNIT
					MIN	MAX	
V _{IH}	Input HIGH Voltage (An, \overline{OE})		2.7 – 3.6	0.9 – 3.6	2.0	–	V
			2.3 – 2.7		1.6	–	
			1.4 – 2.3		$0.65 \times V_{CCA}$	–	
			0.9 – 1.4		$0.9 \times V_{CCA}$	–	
V _{IL}	Input LOW voltage (An, \overline{OE})		2.7 – 3.6	0.9 – 3.6	–	0.8	V
			2.3 – 2.7		–	0.7	
			1.4 – 2.3		–	$0.35 \times V_{CCA}$	
			0.9 – 1.5		–	$0.1 \times V_{CCA}$	
V _{OH}	Output HIGH voltage	I _{OH} = –100 μ A; V _I = V _H	0.9 – 3.6	0.9 – 3.6	$V_{CCB} - 0.2$	–	V
		I _{OH} = –0.5 mA; V _I = V _H	0.9	0.9	$0.75 \times V_{CCB}$	–	
		I _{OH} = –2 mA; V _I = V _H	1.4	1.4	1.05	–	
		I _{OH} = –6 mA; V _I = V _H	1.65	1.65	1.25	–	
		I _{OH} = –12 mA; V _I = V _H	2.3	2.3	2.0	–	
		I _{OH} = –12 mA; V _I = V _H	2.3	2.3	1.8	–	
		I _{OH} = –12 mA; V _I = V _H	2.7	2.7	2.2	–	
		I _{OH} = –18 mA; V _I = V _H	2.3	2.3	1.7	–	
		I _{OH} = –24 mA; V _I = V _H	3.0	3.0	2.4	–	
V _{OL}	Output LOW voltage	I _{OH} = 100 μ A; V _I = V _H	0.9 – 3.6	0.9 – 3.6	–	0.2	V
		I _{OH} = 0.5 mA; V _I = V _H	1.1	1.1	–	0.3	
		I _{OH} = 2 mA; V _I = V _H	1.4	1.4	–	0.35	
		I _{OH} = 6 mA; V _I = V _H	1.65	1.65	–	0.3	
		I _{OH} = 12 mA; V _I = V _H	2.3	2.3	–	0.4	
		I _{OH} = 12 mA; V _I = V _H	2.7	2.7	–	0.4	
		I _{OH} = 18 mA; V _I = V _H	2.3	2.3	–	0.6	
		I _{OH} = 18 mA; V _I = V _H	3.0	3.0	–	0.4	
		I _{OH} = 24 mA; V _I = V _H	3.0	3.0	–	0.55	
I _I	Input Leakage Current	V _I = V _{CCA} or GND	0.9 – 3.6	0.9 – 3.6	–1.0	1.5	μ A
I _{OFF}	Power-Off Leakage Current	$\overline{OE} = 0V$	0	0.9 – 3.6	–1.0	1.3	μ A
			0.9 – 3.6	0	–1.0	1.5	
I _{CCA}	Quiescent Supply Current	V _I = V _{CCA} or GND; I _O = 0	0.9 – 3.6	0.9 – 3.6	–	3.0	μ A
I _{CCB}	Quiescent Supply Current	V _I = V _{CCA} or GND; I _O = 0	0.9 – 3.6	0.9 – 3.6	–	3.0	μ A
I _{CCA} + I _{CCB}	Quiescent Supply Current	V _I = V _{CCA} or GND; I _O = 0	0.9 – 3.6	0.9 – 3.6	–	6.0	μ A
ΔI_{CCA}	Increase in I _{CC} per Input Voltage, Other inputs at V _{CCA} or GND	V _I = V _{CCA} – 0.3 V; V _I = V _{CCA} or GND	3.6	3.6	–	5.0	μ A

(1) V_{CCO} is the V_{CC} associated with the output port.

(2) V_{CCI} is the V_{CC} associated with the input port.

ELECTRICAL CHARACTERISTICS^{(1) (2)} (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA} (V)	V _{CCB} (V)	–40°C to 85°C		UNIT
					MIN	MAX	
ΔI_{CCB}	Increase in I_{CC} per Input Voltage, Other inputs at V _{CCA} or GND	V _I = V _{CCA} – 0.3 V; V _I = V _{CCA} or GND	3.6	3.6	–	5.0	μA
I _{OZ}	I/O Tri-State Output Leakage Current	T _A = 25°C, \overline{OE} = 0 V	0.9 – 3.6	0.9 – 3.6	–1.0	1.0	μA

AC ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter	V _{CCA} (V)	V _{CCB} (V)	MIN	MAX	UNIT
t _{PLH} , t _{PHL}	Propagation Delay, A _n to B _n	0.9 – 3.6	0.9 – 3.6		20	nS
		1.2 – 3.6	1.2 – 3.6		7	
		1.8 – 3.6	1.8 – 3.6		3.5	
t _{PZH} , t _{PZL}	Output Enable, \overline{OE} to B _n	0.9 – 3.6	0.9 – 3.6		23	nS
		1.2 – 3.6	1.2 – 3.6		6.5	
		1.8 – 3.6	1.8 – 3.6		4.1	
t _{PHZ} , t _{PLZ}	Output Disable, \overline{OE} to B _n	0.9 – 3.6	0.9 – 3.6		17	nS
		1.2 – 3.6	1.2 – 3.6		7	
		1.8 – 3.6	1.8 – 3.6		4.3	
t _{OSHL} , t _{OSLH}	Output to Output Skew, Time	0.9 – 3.6	0.9 – 3.6		0.15	nS
		1.2 – 3.6	1.2 – 3.6		0.15	
		1.8 – 3.6	1.8 – 3.6		0.15	

Table 1. CAPACITANCE⁽¹⁾

Symbol	Parameter	Test Conditions	TYP ⁽²⁾	Unit
C _{IN}	Control Pin Input Capacitance	V _{CCA} = V _{CCB} = 3.3 V, V _I = 0 V or V _{CCA/B}	3.5	pF
C _{I/O}	I/O Pin Input capacitance	V _{CCA} = V _{CCB} = 3.3 V, V _I = 0 V or V _{CCA/B}	5.0	pF
C _{PD}	Power Dissipation Capacitance	V _{CCA} = V _{CCB} = 3.3 V, V _I = 0 V or V _{CCA/B} , f = 10 MHz	33	pF

- (1) C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I_{CC(operating)} ≈ C_{PD} × V_{CC} × f_{IN} × N_{SW} where I_{CC} = I_{CCA} + I_{CCB} and N_{SW} = total number of outputs switching.
- (2) Typical values are at TA = +25°C.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AVC2T244DQER	ACTIVE	X2SON	DQE	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	VA	Samples
SN74AVC2T244DQMR	ACTIVE	X2SON	DQM	8	3000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	VA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC2T244DQER	X2SON	DQE	8	5000	180.0	8.4	1.2	1.6	0.55	4.0	8.0	Q1
SN74AVC2T244DQMR	X2SON	DQM	8	3000	180.0	8.4	1.57	2.21	0.59	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

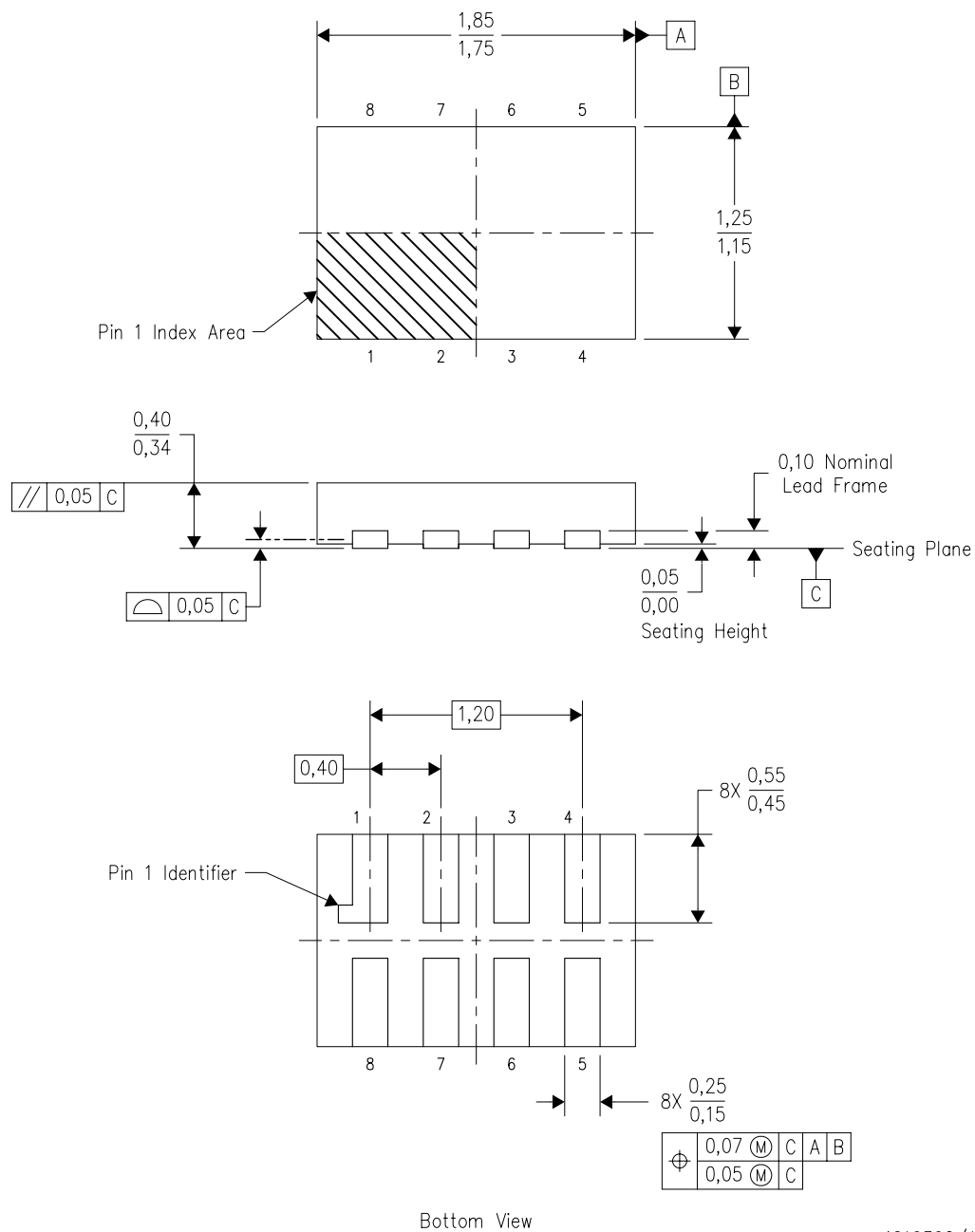


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC2T244DQER	X2SON	DQE	8	5000	202.0	201.0	28.0
SN74AVC2T244DQMR	X2SON	DQM	8	3000	202.0	201.0	28.0

DQM (R-PX2SON-N8)

PLASTIC SMALL OUTLINE NO-LEAD



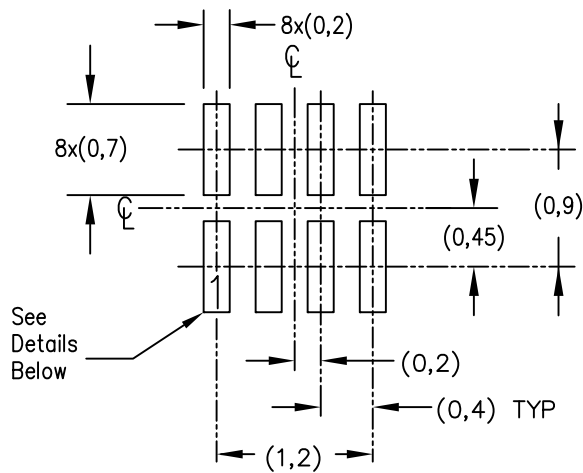
4210302/A 06/2009

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. SON (Small Outline No-Lead) package configuration.

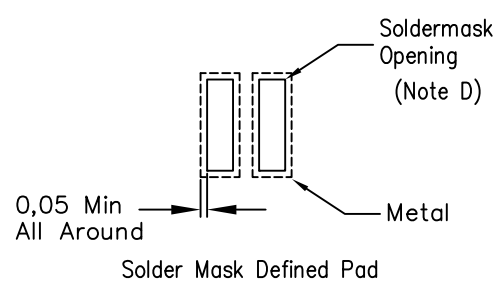
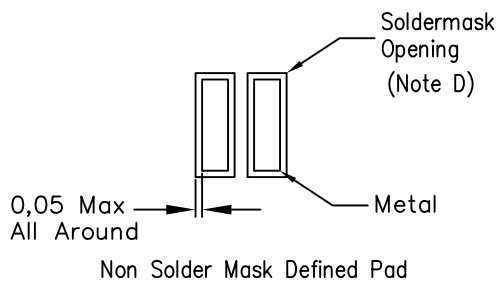
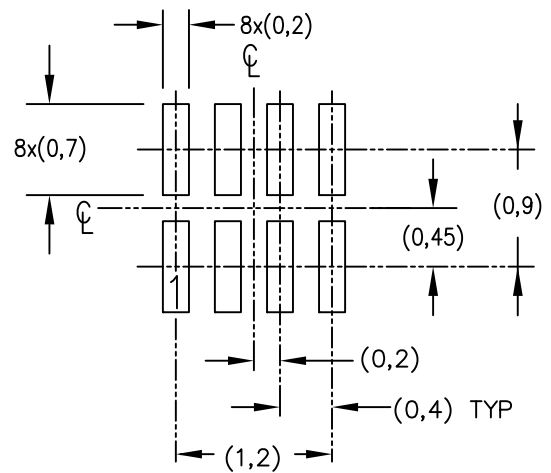
DQM (R-PX2SON-N8)

PLASTIC SMALL OUTLINE NO-LEAD

Example Board Layout



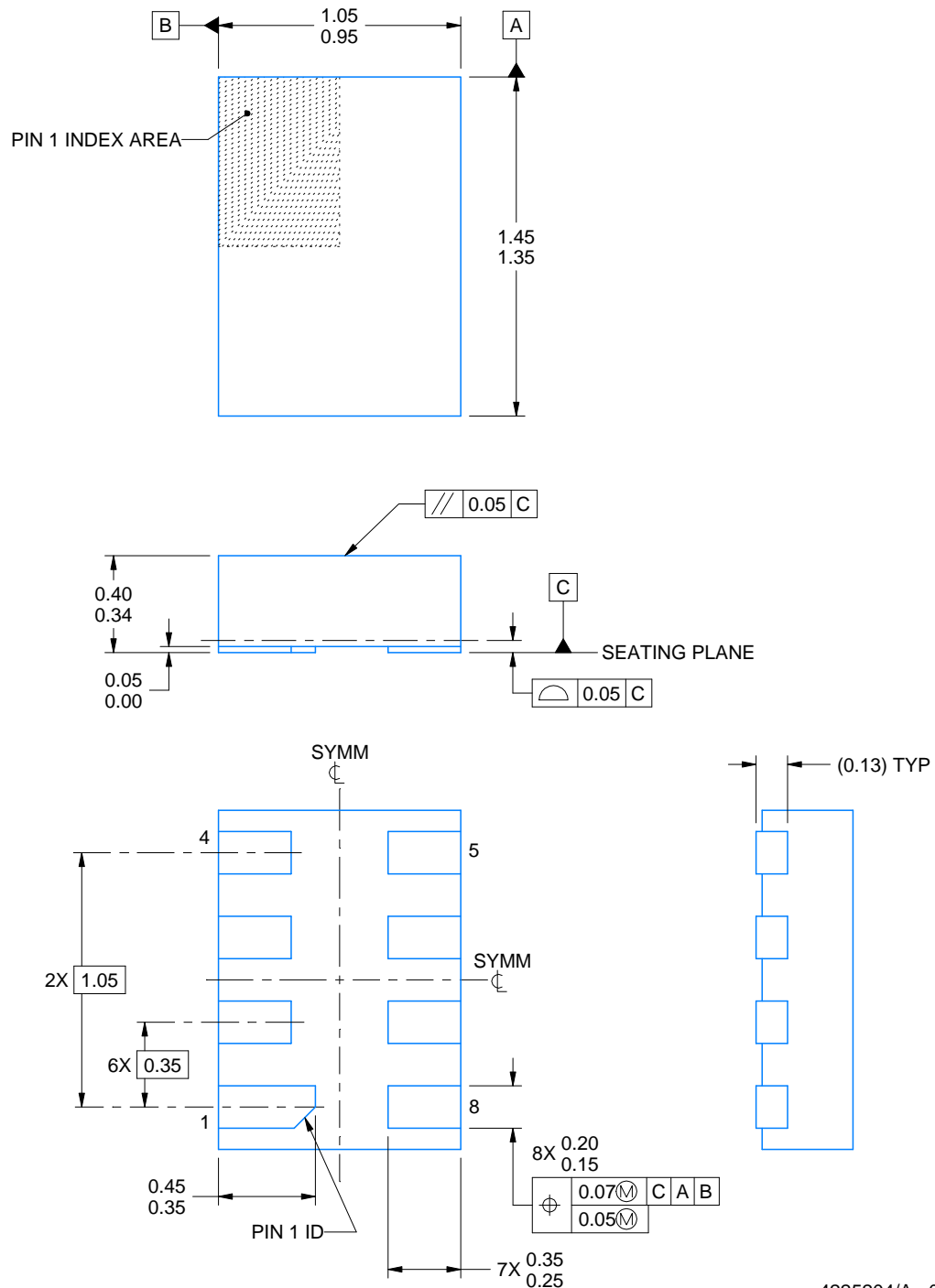
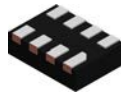
Example Stencil Design
0.1mm Thick Stencil
(Note C)



Solder Mask Details

4218746/A 07/13

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - D. Customers should contact their board fabrication site for recommended solder mask tolerances.



4225204/A 08/2019

NOTES:

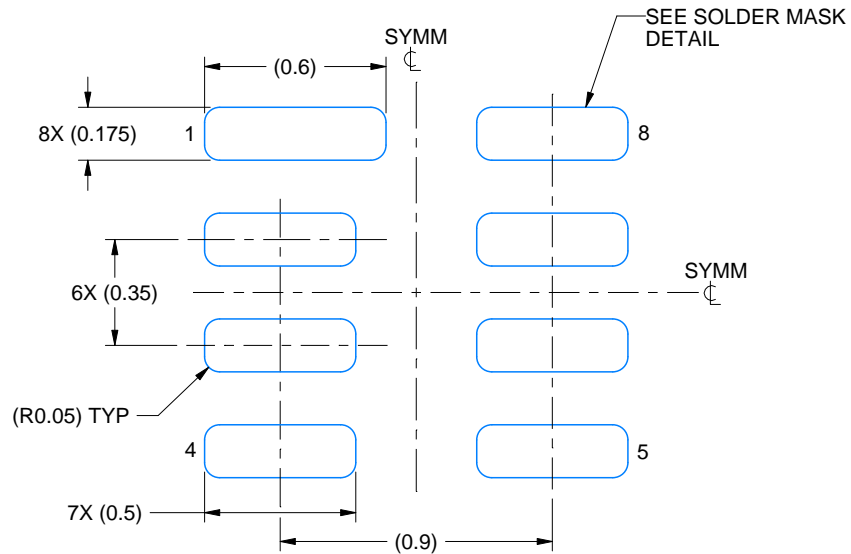
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package complies to JEDEC MO-287 variation X2EAF.

EXAMPLE BOARD LAYOUT

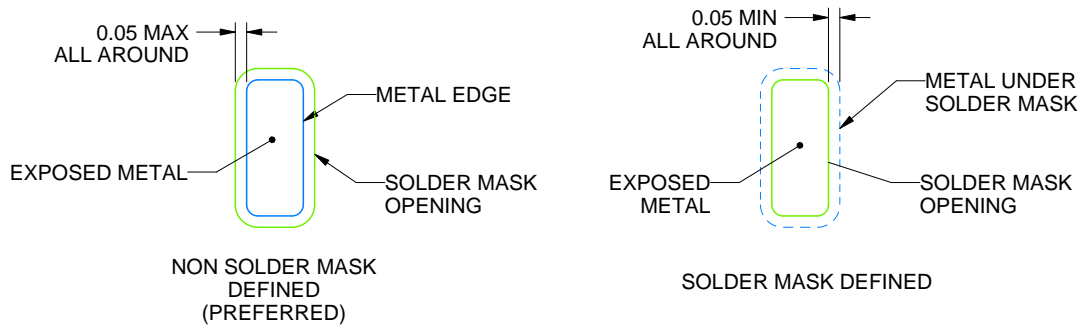
DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 40X



SOLDER MASK DETAILS

4225204/A 08/2019

NOTES: (continued)

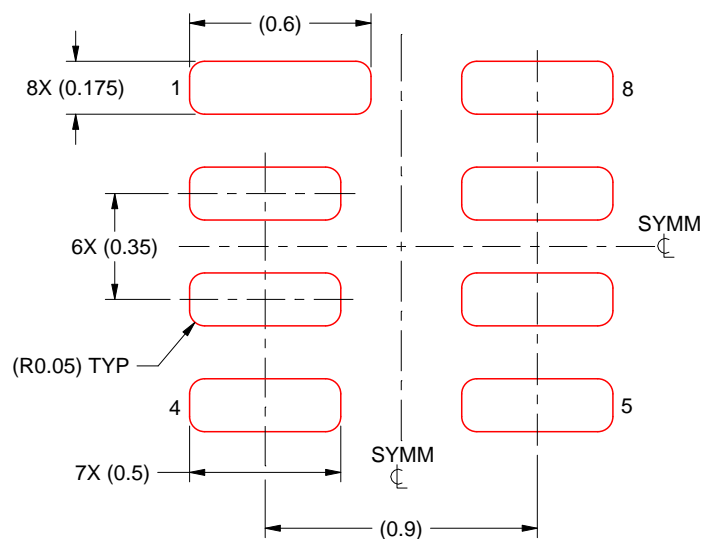
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).

EXAMPLE STENCIL DESIGN

DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 MM THICK STENCIL
SCALE: 40X

4225204/A 08/2019

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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